ΡΛΝ	JIT
	SEMI
	CONDUCTOR

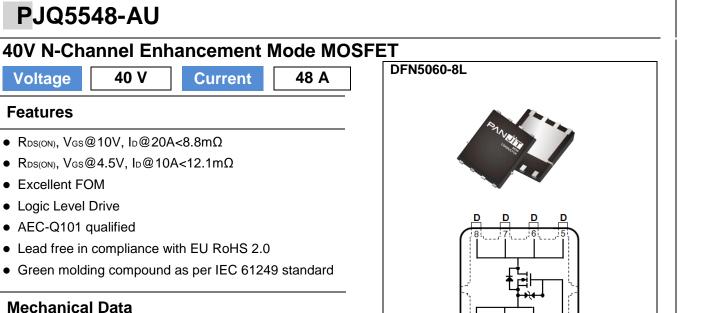
Voltage

Features

• Excellent FOM • Logic Level Drive • AEC-Q101 qualified

PJQ5548-AU

40 V



Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	40	V
Gate-Source Voltage		V _{GS}	±20	V
Continuous Drain Current ^(Note 3)	T _C =25°C		48	
	Tc=100°C	I _D	34	А
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	192	
Power Dissipation	T _C =25°C	D-	36	10/
	Tc=100°C	PD	18	W
Continuous Droin Curront(Note 4)	$T_A=25^{\circ}C$		14.5	٨
Continuous Drain Current ^(Note 4)	T _A =70°C	ID	12	A
Dower Dissinction	T _A =25°C	D-	3.3	W
Power Dissipation	T _A =70°C	PD	2.3	VV
Single Pulse Avalanche Energy ^{(Note}	9 5)	Eas	42	mJ
Operating Junction and Storage Te	emperature Range	TJ,TSTG	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	4.2	°C/W
	Junction to Ambient	R _{θJA}	45	C/VV



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	ss V _{GS} =0V, I _D =250uA 40		-	-	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50uA	1.1	1.6	2.3	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	7	8.8	
		V _{GS} =4.5V, I _D =10A		9.3	12.1	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =40V, V_{GS} =0V	-	-	1	uA
Orte Course Looke as Ourset		V _{GS} =±20V, V _{DS} =0V	-	-	±10	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±10V, V _{DS} =0V	-	-	±1	
Dynamic ^(Note 6)						
Total Gate Charge	Qg		-	13	-	nC
Gate-Source Charge	Qgs	$V_{DS}=32V, I_{D}=20A,$	-	3	-	
Gate-Drain Charge	Q_gd	V _{GS} =10V	-	2	-	
Input Capacitance	Ciss		-	778	-	
Output Capacitance	Coss	$V_{DS}=25V, V_{GS}=0V,$	-	180	-	pF
Reverse Transfer Capacitance	Crss	f=1MHz	-	25	-	
Gate resistance	Rg	f=1MHz	-	1.6	-	Ω
Turn-On Delay Time	td _(on)		-	9	-	
Turn-On Rise Time	tr	V _{DS} =32V, I _D =20A,	-	3	-	
Turn-Off Delay Time	td _(off)	V _{GS} =10V, R _G =3Ω	-	21	-	ns
Turn-Off Fall Time	tf		-	3	-	
Drain-Source Diode	•	·		•	•	
Diode Forward Current	I _S	T _c =25°C	-	-	48	
Pulsed Diode Forward Current	I _{SM}	1C=20 C	-	-	192	A
Diode Forward Voltage	V _{SD}	Is=20A, V _{GS} =0V	-	0.9	1.3	V
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =20A	-	21	-	ns
Reverse Recovery Charge	Qrr	dl _s /dt=100A/us	-	10	-	nC

NOTES :

- 1. Pulse width<100us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}$ =4.2°C/W.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS} =13A, V_{DD} =30V, V_{GS} =10V, Starting T_J =25°C.
- 6. Guaranteed by design, not subject to production testing.



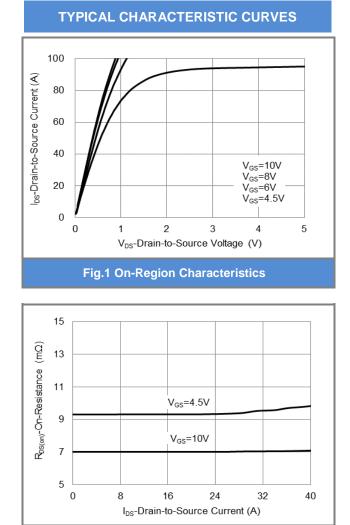
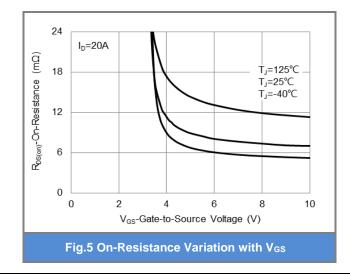


Fig.3 On-Resistance vs. Drain Current



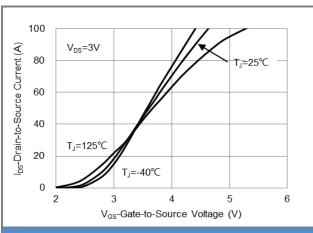


Fig.2 Transfer Characteristics

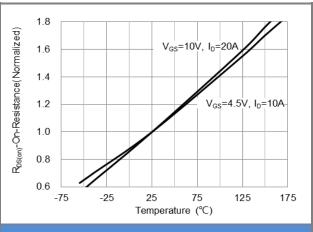
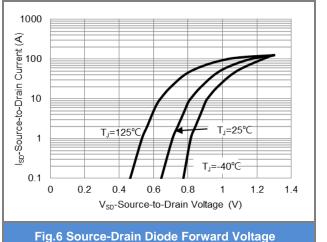


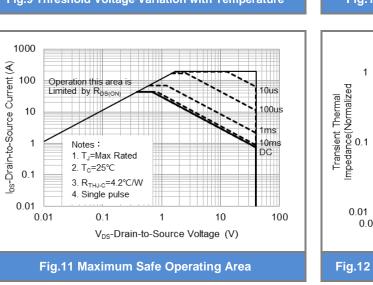
Fig.4 On-Resistance vs. Junction temperature

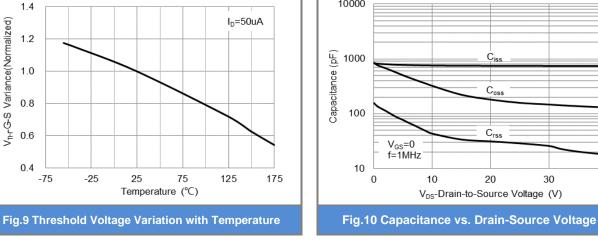


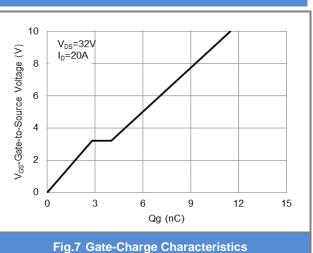
April 18,2023

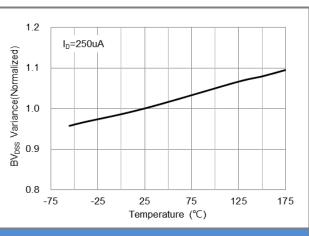
V_{TH}-G-S Variance(Normalized)

0.2 0.1 0.05 T_{J,PK}=T_C+P_{DM}*Z_{TH-JC}*R_{TH-JC} 0.02 R_{TH-JC}=4.2°C/W T_c=25℃ Single Pulse 0.00001 0.0001 0.001 0.01 0.1 t, Pulse Width (sec) Fig.12 Normalized Transient Thermal Impedance











Coss

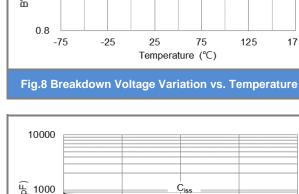
Crss

20

V_{DS}-Drain-to-Source Voltage (V)

30

40



10

D=0.5



PJQ5548-AU



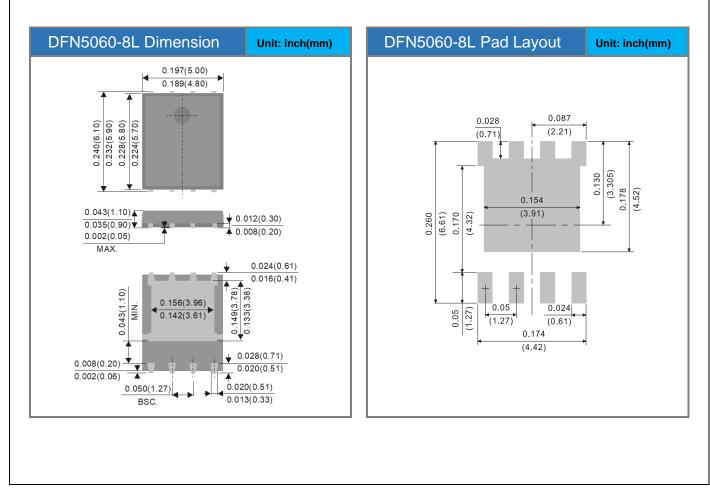




Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ5548-AU	DFN5060-8L	3K pcs / 13" reel	Q5548

Packaging Information & Mounting Pad Layout





Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.